NSN 5961-01-382-7610

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Internal Configuration:

Junction contact

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

16.0 collector-to-emitter, substaining voltage, base open-circuited and 36.0 collector to base voltage/static/emitter open and 4.0 emitter to

base voltage, static, collector open

Current Rating Per Characteristic:

400.00 milliamperes source cutoff current

Power Rating Per Characteristic:

3.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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